



NC7S32

TinyLogic™ HS 2-Input OR Gate

General Description

The NC7S32 is a single 2-Input high performance CMOS OR Gate. Advanced Silicon Gate CMOS fabrication assures high speed and low power circuit operation over a broad V_{CC} range. ESD protection diodes inherently guard both inputs and output with respect to the V_{CC} and GND rails. Three stages of gain between inputs and outputs assures high noise immunity and reduced sensitivity to input edge rate.

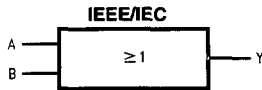
Features

- Space saving SOT23 or SC70 5-lead package
- High Speed; t_{PD} 3.5 ns typ
- Low Quiescent Power; $I_{CC} < 1 \mu A$
- Balanced Output Drive; 2 mA I_{OL} , -2 mA I_{OH}
- Broad V_{CC} Operating Range: 2V-6V
- Balanced Propagation Delays
- Specified for 3V Operation

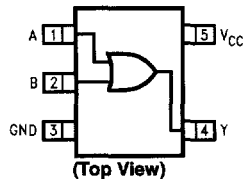
Ordering Code:

Order Number	Package Number	Package Top Mark	Package Description	Supplied As
NC7S32M5	MA05B	7S32	5-Lead SOT23, JEDEC MO-178, 1.6mm	250 Units on Tape and Reel
NC7S32M5X	MA05B	7S32	5-Lead SOT23, JEDEC MO-178, 1.6mm	3k Units on Tape and Reel
NC7S32M5	MAA05A	S32	5-Lead SC70, EIAJ SC-88a, 1.25mm Wide	250 Units on Tape and Reel
NC7S32M5X	MAA05A	S32	5-Lead SC70, EIAJ SC-88a, 1.25mm Wide	3k Units on Tape and Reel

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A, B	Inputs
Y	Output

Function Table

$Y = A + B$

Inputs		Output
A	B	Y
L	L	L
L	H	H
H	L	H
H	H	H

H = HIGH Logic Level
L = LOW Logic Level

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Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	-0.5V to +7.0V
DC Input Diode Current (I_{IK})	
@ $V_{IN} \leq -0.5V$	-20 mA
@ $V_{IN} \geq V_{CC} + 0.5V$	+20 mA
DC Input Voltage (V_{IN})	-0.5V to $V_{CC} + 0.5V$
DC Output Diode Current (I_{OK})	
@ $V_{OUT} < -0.5V$	-20 mA
@ $V_{OUT} > V_{CC} + 0.5V$	+20 mA
DC Output Voltage (V_{OUT})	-0.5V to $V_{CC} + 0.5V$
DC Output Source or Sink Current (I_{OUT})	± 12.5 mA
DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})	± 25 mA
Storage Temperature (T_{STG})	-65°C to +150°C
Junction Temperature (T_J)	150°C
Lead Temperature (T_L) (Soldering, 10 seconds)	260°C
Power Dissipation (P_D) @ +85°C	
SOT23-5	200 mW
SC70-5	150 mW

Recommended Operating Conditions

Supply Voltage (V_{CC})	2.0V to 6.0V
Input Voltage (V_{IN})	0V to V_{CC}
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_A)	-40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} @ 2.0V	0 to 1000 ns
V_{CC} @ 3.0V	0 to 750 ns
V_{CC} @ 4.5V	0 to 500 ns
V_{CC} @ 6.0V	0 to 400 ns
Thermal Resistance (θ_{JA})	
SOT23-5	300°C/W
SC70-5	425°C/W

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, with out exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of circuits outside the databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = +25^\circ C$			$T_A = -40^\circ C$ to $+85^\circ C$		Units	Condition	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input Voltage	2.0	1.50			1.50		V		
		3.0-6.0	$0.7V_{CC}$			$0.7V_{CC}$				
V_{IL}	LOW Level Input Voltage	2.0			0.50		0.50	V		
		3.0-6.0			$0.3 V_{CC}$		$0.3 V_{CC}$			
V_{OH}	HIGH Level Output Voltage	2.0	1.90	2.0		1.90		V	$I_{OH} = -20$ mA $V_{IN} = V_{IH}$	
		3.0	2.90	3.0		2.90				
		4.5	4.40	4.5		4.40				
		6.0	5.90	6.0		5.90				
			3.0	2.68	2.85		2.63		V	$V_{IN} = V_{IH}$ $I_{OH} = -1.3$ mA $I_{OH} = -2$ mA $I_{OH} = -2.6$ mA
			4.5	4.18	4.35		4.13			
			6.0	5.68	5.85		5.63			
V_{OL}	LOW Level Output Voltage	2.0		0.0	0.10		0.10	V	$I_{OL} = 20$ μ A $V_{IN} = V_{IL}$	
		3.0		0.0	0.10		0.10			
		4.5		0.0	0.10		0.10			
		6.0		0.0	0.10		0.10			
			3.0		0.1	0.26		0.33	V	$V_{IN} = V_{IL}$ $I_{OL} = 1.3$ mA $I_{OL} = 2$ mA $I_{OL} = 2.6$ mA
			4.5		0.1	0.26		0.33		
			6.0		0.1	0.26		0.33		
I_{IN}	Input Leakage Current	6.0		± 0.1		± 1.0	μ A	$V_{IN} = V_{CC}, GND$		
I_{CC}	Quiescent Supply Current	6.0		1.0		10.0	μ A	$V_{IN} = V_{CC}, GND$		

AC Electrical Characteristics

Symbol	Parameter	V _{CC} (V)	T _A = +25°C			T _A = -40°C to +85°C		Units	Conditions	Fig. No.
			Min	Typ	Max	Min	Max			
t _{PLH} , t _{PHL}	Propagation Delay	5.0		3.5	15			ns	C _L = 15 pF	Figure 1
		2.0		20	100		125		C _L = 50 pF	Figure 3
		3.0		12	27		35	ns		
		4.5		8	20		25			
		6.0		7	17		21			
t _{TLH} , t _{THL}	Output Transition Time	5.0		3.0	10			ns	C _L = 15 pF	Figure 1
		2.0		25	125		155		C _L = 50 pF	Figure 3
		3.0		16	35		45	ns		
		4.5		11	25		31			
		6.0		9	21		26			
C _{IN}	Input Capacitance	Open		2	10		10	pF		
C _{PD}	Power Dissipation Capacitance	5.0		6				pF	(Note 2)	Figure 2

Note 2: C_{PD} is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current consumption (I_{CCD}) at no output loading and operating at 50% duty cycle. (See Figure 2) C_{PD} is related to I_{CCD} dynamic operating current by the expression:
 $I_{CCD} = (C_{PD}) (V_{CC}) (f_{IN}) + (I_{CC}^{static})$.

AC Loading and Waveforms

